

DATA SHEET

For a complete data sheet, please also download:

- The IC06 74HC/HCT/HCU/HCMOS Logic Family Specifications
- The IC06 74HC/HCT/HCU/HCMOS Logic Package Information
- The IC06 74HC/HCT/HCU/HCMOS Logic Package Outlines

74HC/HCT4060

14-stage binary ripple counter with oscillator

Product specification
File under Integrated Circuits, IC06

December 1990

14-stage binary ripple counter with oscillator**74HC/HCT4060****FEATURES**

- All active components on chip
- RC or crystal oscillator configuration
- Output capability: standard (except for R_{TC} and C_{TC})
- I_{CC} category: MSI

GENERAL DESCRIPTION

The 74HC/HCT4060 are high-speed Si-gate CMOS devices and are pin compatible with "4060" of the "4000B" series. They are specified in compliance with JEDEC standard no. 7A.

The 74HC/HCT4060 are 14-stage ripple-carry counter/dividers and oscillators with three oscillator

terminals (RS , R_{TC} and C_{TC}), ten buffered outputs (Q_3 to Q_9 and Q_{11} to Q_{13}) and an overriding asynchronous master reset (MR).

The oscillator configuration allows design of either RC or crystal oscillator circuits. The oscillator may be replaced by an external clock signal at input RS. In this case keep the other oscillator pins (R_{TC} and C_{TC}) floating.

The counter advances on the negative-going transition of RS. A HIGH level on MR resets the counter (Q_3 to Q_9 and Q_{11} to Q_{13} = LOW), independent of other input conditions.

In the HCT version, the MR input is TTL compatible, but the RS input has CMOS input switching levels and can be driven by a TTL output by using a pull-up resistor to V_{CC} .

QUICK REFERENCE DATA

$GND = 0 \text{ V}$; $T_{amb} = 25^\circ\text{C}$; $t_r = t_f = 6 \text{ ns}$

SYMBOL	PARAMETER	CONDITIONS	TYPICAL		UNIT
			HC	HCT	
t_{PHL}/t_{PLH}	propagation delay RS to Q_3	$C_L = 15 \text{ pF}$; $V_{CC} = 5 \text{ V}$	31	31	ns
	Q_n to Q_{n+1}		6	6	ns
	MR to Q_n		17	18	ns
	f_{max}		87	88	MHz
C_I	input capacitance		3.5	3.5	pF
C_{PD}	power dissipation capacitance per package	notes 1, 2 and 3	40	40	pF

Notes

1. C_{PD} is used to determine the dynamic power dissipation (P_D in μW):

$$P_D = C_{PD} \times V_{CC}^2 \times f_i + \sum (C_L \times V_{CC}^2 \times f_o) \text{ where:}$$

f_i = input frequency in MHz

f_o = output frequency in MHz

$\sum (C_L \times V_{CC}^2 \times f_o)$ = sum of outputs

C_L = output load capacitance in pF

V_{CC} = supply voltage in V

2. For HC the condition is $V_I = GND$ to V_{CC}

For HCT the condition is $V_I = GND$ to $V_{CC} - 1.5 \text{ V}$

3. For formula on dynamic power dissipation see next pages.

ORDERING INFORMATION

See "*74HC/HCT/HCU/HCMOS Logic Package Information*".

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PIN DESCRIPTION

PIN NO.	SYMBOL	NAME AND FUNCTION
1, 2, 3	Q_{11} to Q_{13}	counter outputs
7, 5, 4, 6, 14, 13, 15	Q_3 to Q_9	counter outputs
8	GND	ground (0 V)
9	CTC	external capacitor connection
10	RTC	external resistor connection
11	RS	clock input/oscillator pin
12	MR	master reset
16	V _{CC}	positive supply voltage

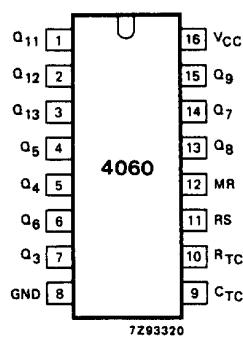


Fig.1 Pin configuration.

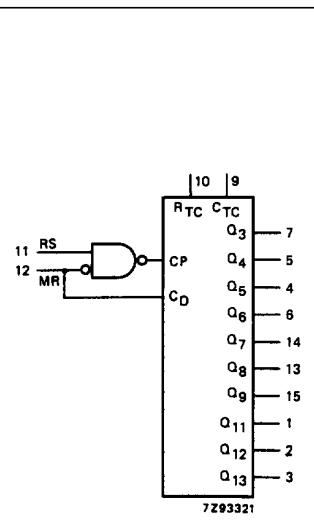


Fig.2 Logic symbol.

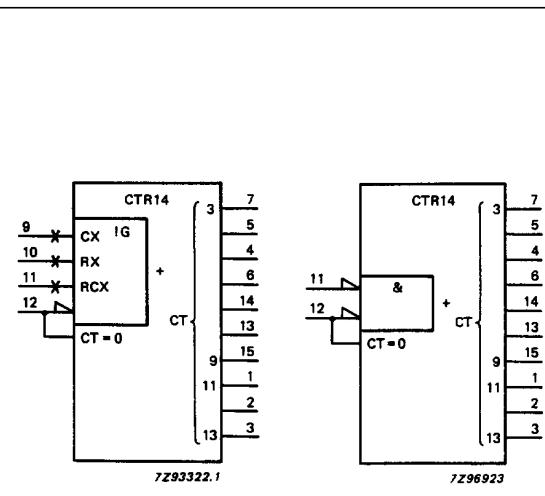


Fig.3 IEC logic symbol.

14-stage binary ripple counter with oscillator

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DYNAMIC POWER DISSIPATION FOR 74HC

PARAMETER	V _{CC} (V)	TYPICAL FORMULA FOR P _D (μ W) (note 1)
total dynamic power dissipation when using the on-chip oscillator (P _D)	2.0	$C_{PD} \times f_{osc} \times V_{CC}^2 + \sum (C_L \times V_{CC}^2 \times f_o) + 2C_t \times V_{CC}^2 \times f_{osc} + 60 \times V_{CC}$
	4.5	$C_{PD} \times f_{osc} \times V_{CC}^2 + \sum (C_L \times V_{CC}^2 \times f_o) + 2C_t \times V_{CC}^2 \times f_{osc} + 1\,750 \times V_{CC}$
	6.0	$C_{PD} \times f_{osc} \times V_{CC}^2 + \sum (C_L \times V_{CC}^2 \times f_o) + 2C_t \times V_{CC}^2 \times f_{osc} + 3\,800 \times V_{CC}$

Note

1. GND = 0 V; T_{amb} = 25 °C

DYNAMIC POWER DISSIPATION FOR 74HCT

PARAMETER	V _{CC} (V)	TYPICAL FORMULA FOR P _D (μ W) (note 1)
total dynamic power dissipation when using the on-chip oscillator (P _D)	4.5	$C_{PD} \times f_{osc} \times V_{CC}^2 + \sum (C_L \times V_{CC}^2 \times f_o) + 2C_t \times V_{CC}^2 \times f_{osc} + 1\,750 \times V_{CC}$

Notes

1. GND = 0 V; T_{amb} = 25 °C
 2. Where: f_o = output frequency in MHz

f_{osc} = oscillator frequency in MHz

$\sum (C_L \times V_{CC}^2 \times f_o)$ = sum of outputs

C_L = output load capacitance in pF

C_t = timing capacitance in pF

V_{CC} = supply voltage in V

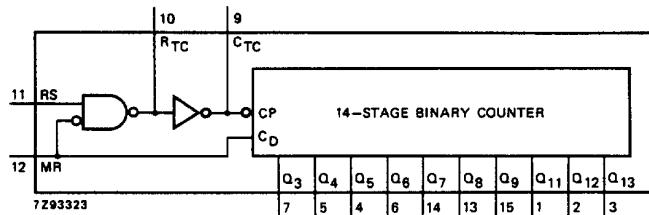


Fig.4 Functional diagram.

APPLICATIONS

- Control counters
- Timers
- Frequency dividers
- Time-delay circuits

14-stage binary ripple counter with oscillator

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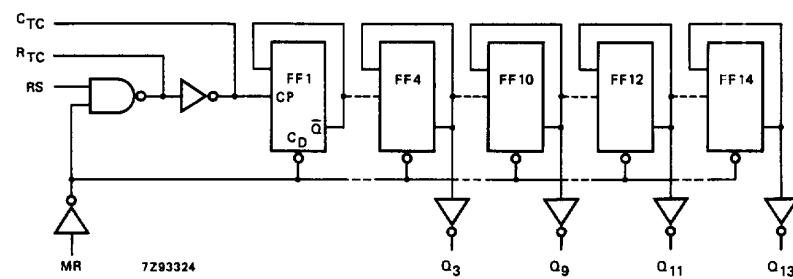


Fig.5 Logic diagram.

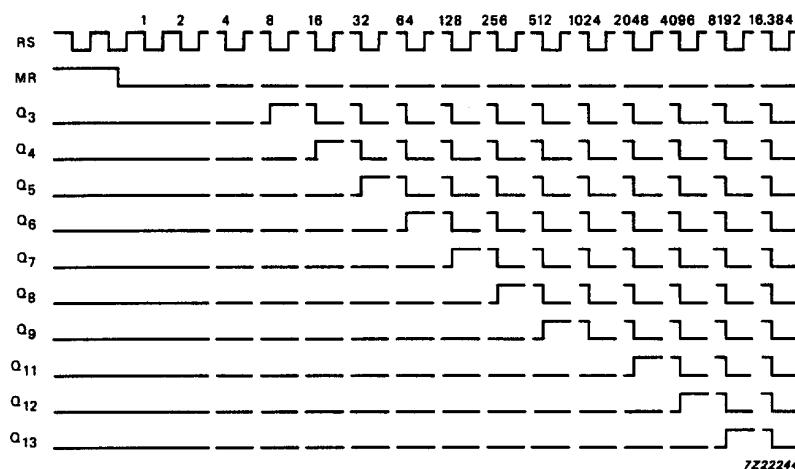


Fig.6 Timing diagram.

14-stage binary ripple counter with oscillator

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DC CHARACTERISTICS FOR 74HC

Output capability: standard (except for R_{TC} and C_{TC}) I_{CC} category: MSI

Voltages are referenced to GND (ground = 0 V)

SYM-BOL	PARAMETER	T_{amb} ($^{\circ}$ C)						UNIT	TEST CONDITIONS					
		74HC							V _{CC} (V)	V _I	OTHER			
		+25			-40 to +85		-40 to +125							
		min.	typ.	max.	min.	max.	min.	max.						
V _{IH}	HIGH level input voltage MR input	1.5 3.15 4.2	1.3 2.4 3.1		1.5 3.15 4.2		1.5 3.15 4.2		V	2.0 4.5 6.0				
V _{IL}	LOW level input voltage MR input		0.8 2.1 2.8	0.5 1.35 1.8		0.5 1.35 1.8		0.5 1.35 1.8	V	2.0 4.5 6.0				
V _{IH}	HIGH level input voltage RS input	1.7 3.6 4.8			1.7 3.6 4.8		1.7 3.6 4.8		V	2.0 4.5 6.0				
V _{IL}	LOW level input voltage RS input			0.3 0.9 1.2		0.3 0.9 1.2		0.3 0.9 1.2	V	2.0 4.5 6.0				
V _{OH}	HIGH level output voltage R_{TC} output	3.98 5.48			3.84 5.34		3.7 5.2		V	4.5 6.0	RS=GND and MR=GND	-I _O = 2.6 mA -I _O = 3.3 mA		
		3.98 5.48			3.84 5.34		3.7 5.2		V	4.5 6.0	RS=V _{CC} and MR=V _{CC}	-I _O = 0.65 mA -I _O = 0.85 mA		
		1.9 4.4 5.9	2.0 4.5 6.0		1.9 4.4 5.9		1.9 4.4 5.9		V	2.0 4.5 6.0	RS=GND and MR=GND	-I _O = 20 μ A -I _O = 20 μ A -I _O = 20 μ A		
		1.9 4.4 5.9	2.0 4.5 6.0		1.9 4.4 5.9		1.9 4.4 5.9		V	2.0 4.5 6.0	RS=V _{CC} and MR=V _{CC}	-I _O = 20 μ A -I _O = 20 μ A -I _O = 20 μ A		
V _{OH}	HIGH level output voltage C_{TC} output	3.98 5.48			3.84 5.34		3.7 5.2		V	4.5 6.0	RS=V _{IH} and MR=V _{IL}	-I _O = 3.2 mA -I _O = 4.2 mA		
V _{OH}	HIGH level output voltage except R_{TC} output	1.9 4.4 5.9	2.0 4.5 6.0		1.9 4.4 5.9		1.9 4.4 5.9		V	2.0 4.5 6.0	V _{IH} or V _{IL}	-I _O = 20 μ A -I _O = 20 μ A -I _O = 20 μ A		
V _{OH}	HIGH level output voltage except R_{TC} and C_{TC} outputs	3.98 5.48			3.84 5.34		3.7 5.2		V	4.5 6.0	V _{IH} or V _{IL}	-I _O = 4.0 mA -I _O = 5.2 mA		
V _{OL}	LOW level output voltage R_{TC} output			0.26 0.26		0.33 0.33		0.4 0.4		4.5 6.0	RS=V _{CC} and MR=GND	I _O = 2.6 mA I _O = 3.3 mA		
				0 0 0	0.1 0.1 0.1		0.1 0.1 0.1	0.1 0.1 0.1	V	2.0 4.5 6.0	RS=V _{CC} and MR=GND	I _O = 20 μ A I _O = 20 μ A I _O = 20 μ A		

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SYM-BOL	PARAMETER	T _{amb} (°C)						UNIT	TEST CONDITIONS					
		74HC							V _{CC} (V)	V _I	OTHER			
		+25			−40 to +85		−40 to +125							
		min.	typ.	max.	min.	max.	min.	max.						
V _{OL}	LOW level output voltage C _{TC} output			0.26 0.26		0.33 0.33		0.4 0.4	V 4.5 6.0	RS=V _{IL} and MR=V _{IH}	I _O = 3.2 mA I _O = 4.2 mA			
V _{OL}	LOW level output voltage except R _{TC} output	0 0 0	0.1 0.1 0.1		0.1 0.1 0.1		0.1 0.1 0.1	V 2.0 4.5 6.0	V _{IH} or V _{IL}	I _O = 20 μA I _O = 20 μA I _O = 20 μA				
V _{OL}	LOW level output voltage except R _{TC} and C _{TC} outputs			0.26 0.26		0.33 0.33		0.4 0.4	V 4.5 6.0	V _{IH} or V _{IL}	I _O = 4.0 mA I _O = 5.2 mA			
±I _I	input leakage current			0.1		1.0		1.0	μA 6.0	V _{CC} or GND				
I _{CC}	quiescent supply current			8.0		80.0		160.0	μA 6.0	V _{CC} or GND	I _O = 0			

14-stage binary ripple counter with oscillator

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AC CHARACTERISTICS FOR 74HC

GND = 0 V; $t_r = t_f = 6$ ns; $C_L = 50$ pF

SYMBOL	PARAMETER	T_{amb} ($^{\circ}$ C)						UNIT	TEST CONDITIONS			
		74HC							V _{CC} (V)	WAVEFORMS		
		+25			-40 to +85		-40 to +125					
		min.	typ.	max.	min.	max.	min.	max.				
t_{PHL}/t_{PLH}	propagation delay RS to Q_3	99 36 29	300 60 51		375 75 64		450 90 77		ns	2.0 4.5 6.0		
t_{PHL}/t_{PLH}	propagation delay Q_n to Q_{n+1}	22 8 6	80 16 14		100 20 17		120 24 20		ns	2.0 4.5 6.0		
t_{PHL}	propagation delay MR to Q_n	55 20 16	175 35 30		220 44 37		265 53 45		ns	2.0 4.5 6.0		
t_{TLH}/t_{TLL}	output transition time	19 7 6	75 15 13		95 19 16		110 22 19		ns	2.0 4.5 6.0		
t_W	clock pulse width RS; HIGH or LOW	80 16 14	17 6 5		100 20 17		120 24 20		ns	2.0 4.5 6.0		
t_W	master reset pulse width MR; HIGH	80 16 14	25 9 7		100 20 17		120 24 20		ns	2.0 4.5 6.0		
t_{rem}	removal time MR to RS	100 20 17	28 10 8		125 25 21		150 30 26		ns	2.0 4.5 6.0		
f_{max}	maximum clock pulse frequency	6.0 30 35	26 80 95		4.8 24 28		4.0 20 24		MHz	2.0 4.5 6.0		

14-stage binary ripple counter with oscillator

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DC CHARACTERISTICS FOR 74HCT

Output capability: standard (except for R_{TC} and C_{TC})

I_{CC} category: MSI

Voltages are referenced to GND (ground = 0 V)

SYMBOL	PARAMETER	T_{amb} ($^{\circ}$ C)						UNIT	TEST CONDITIONS					
		74HCT							V _{CC} (V)	V _I	OTHER			
		+25		-40 to +85		-40 to +125								
		min.	typ.	max.	min.	max.	min.	max.						
V _{IH}	HIGH level input voltage	2.0			2.0		2.0		V	4.5 to 5.5		note 2		
V _{IL}	LOW level input voltage			0.8		0.8		0.8	V	4.5 to 5.5		note 2		
V _{OH}	HIGH level output voltage R_{TC} output	3.98			3.84		3.7		V	4.5	RS=GND and MR=GND	-I _O = 2.6 mA		
		3.98			3.84		3.7		V	4.5	RS = V _{CC} and MR = V _{CC}	-I _O = 0.65 mA		
		4.4	4.5		4.4		4.4		V	4.5	RS=GND and MR=GND	-I _O = 20 μ A		
		4.4	4.5		4.4		4.4		V	4.5	RS=V _{CC} and MR=V _{CC}	-I _O = 20 μ A		
V _{OH}	HIGH level output voltage C_{TC} output	3.98			3.84		3.7		V	4.5	RS = V _{IH} and MR = V _{IL}	-I _O = 3.2 mA		
V _{OH}	HIGH level output voltage except R_{TC} output	4.4	4.5		4.4		4.4		V	4.5	V _{IH} or V _{IL}	-I _O = 20 μ A		
V _{OH}	HIGH level output voltage except R_{TC} and C_{TC} outputs	3.98			3.84		3.7		V	4.5	V _{IH} or V _{IL}	-I _O = 4.0 mA		
V _{OL}	LOW level output voltage R_{TC} output			0.26		0.33		0.4	V	4.5	RS=V _{CC} and MR=GND	I _O = 2.6 mA		
			0	0.1		0.1		0.1	V	4.5	RS=V _{CC} and MR=GND	I _O = 20 μ A		
V _{OL}	LOW level output voltage C_{TC} output			0.26		0.33		0.4	V	4.5	RS = V _{IL} and MR = V _{IH}	I _O = 3.2 mA		
V _{OL}	LOW level output voltage except R_{TC} output		0	0.1		0.1		0.1	V	4.5	V _{IH} or V _{IL}	I _O = 20 μ A		
V _{OL}	LOW level output voltage except R_{TC} and C_{TC} outputs			0.26		0.33		0.4	V	4.5	V _{IH} or V _{IL}	I _O = 4.0 mA		
$\pm I$	input leakage current			0.1		1.0		1.0	μ A	5.5	V _{CC} or GND			
I_{CC}	quiescent supply current			8.0		80.0		160.0	μ A	5.5	V _{CC} or GND	I _O = 0		
ΔI_{CC}	additional quiescent supply current per input pin for unit load coefficient is 1 (note 1)		100	360		450		490	μ A	4.5 to 5.5	V _{CC} - 2.1 V	other inputs at V _{CC} or GND; I _O = 0		

14-stage binary ripple counter with oscillator

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Notes

1. The value of additional quiescent supply current (ΔI_{CC}) for a unit load of 1 is given here.
To determine ΔI_{CC} per input, multiply this value by the unit load coefficient shown in the table below.
2. Only input MR (pin 12) has TTL input switching levels for the HCT versions.

INPUT	UNIT LOAD COEFFICIENT
MR	0.40

AC CHARACTERISTICS FOR 74HCTGND = 0 V; $t_r = t_f = 6$ ns; $C_L = 50$ pF

SYMBOL	PARAMETER	T_{amb} (°C)							UNIT	TEST CONDITIONS				
		74HCT								V _{CC} (V)	WAVEFORMS			
		+25			−40 to +85		−40 to +125							
		min.	typ.	max.	min.	max.	min.	max.						
t_{PHL}/t_{PLH}	propagation delay RS to Q_3		33	66		83		99	ns	4.5	Fig.12			
t_{PHL}/t_{PLH}	propagation delay Q_n to Q_{n+1}		8	16		20		24	ns	4.5	Fig.14			
t_{PHL}	propagation delay MR to Q_n		21	44		55		66	ns	4.5	Fig.13			
t_{THL}/t_{TLH}	output transition time		7	15		19		22	ns	4.5	Fig.12			
t_W	clock pulse width RS; HIGH or LOW	16	6		20		24		ns	4.5	Fig.12			
t_W	master reset pulse width MR; HIGH	16	6		20		24		ns	4.5	Fig.13			
t_{rem}	removal time MR to RS	26	13		33		39		ns	4.5	Fig.13			
f_{max}	maximum clock pulse frequency	30	80		24		20		MHz	4.5	Fig.12			

14-stage binary ripple counter with oscillator

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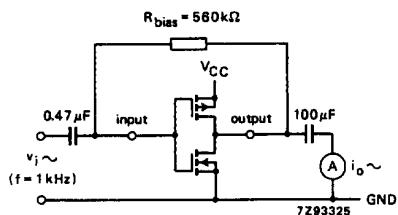


Fig.7 Test set-up for measuring forward transconductance $g_{fs} = d i_o / d v_i$ at v_o is constant (see also graph Fig.8); MR = LOW.

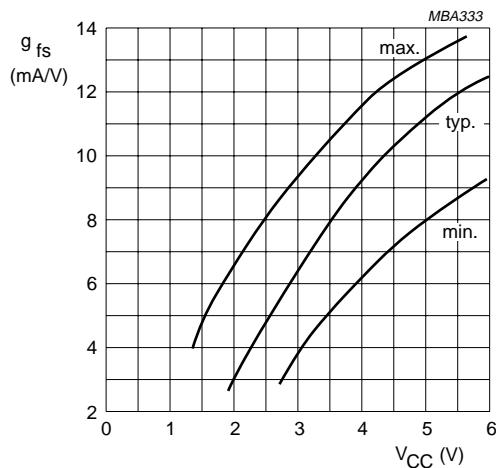


Fig.8 Typical forward transconductance g_{fs} as a function of the supply voltage V_{CC} at $T_{amb} = 25^\circ C$.

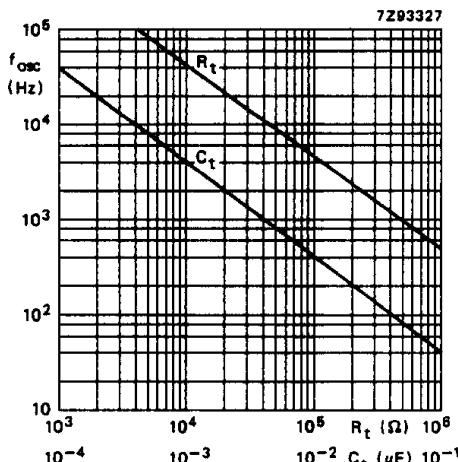
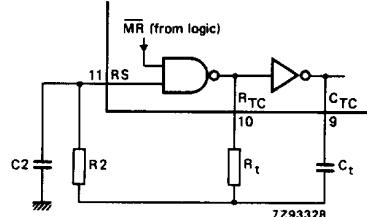


Fig.9 RC oscillator frequency as a function of R_t and C_t at $V_{CC} = 2.0$ to 6.0 V; $T_{amb} = 25^\circ C$. C_t curve at $R_t = 100$ kΩ; $R_2 = 200$ kΩ. R_t curve at $C_t = 1$ nF; $R_2 = 2 \times R_t$.

RC OSCILLATOR



Typical formula for oscillator frequency:

$$f_{osc} = \frac{1}{2.5 \times R_t \times C_t}$$

Fig.10 Example of a RC oscillator.

TIMING COMPONENT LIMITATIONS

The oscillator frequency is mainly determined by $R_t C_t$, provided $R_2 \approx 2R_t$ and $R_2 C_2 \ll R_t C_t$. The function of R_2 is to minimize the influence of the forward voltage across the input protection diodes on the frequency. The stray capacitance C_2 should be kept as small as possible. In consideration of accuracy, C_t must be larger than the inherent stray capacitance. R_t must be larger than the "ON" resistance in series with it, which typically is 280 Ω at $V_{CC} = 2.0$ V, 130 Ω at $V_{CC} = 4.5$ V and 100 Ω at $V_{CC} = 6.0$ V.

The recommended values for these components to maintain agreement with the typical oscillation formula are:
 $C_t > 50$ pF, up to any practical value,
 10 kΩ < R_t < 1 MΩ.

In order to avoid start-up problems, $R_t \geq 1$ kΩ.

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TYPICAL CRYSTAL OSCILLATOR

In Fig.11, R2 is the power limiting resistor. For starting and maintaining oscillation a minimum transconductance is necessary, so R2 should not be too large. A practical value for R2 is 2.2 k Ω .

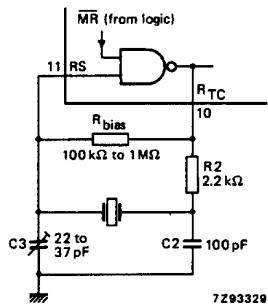
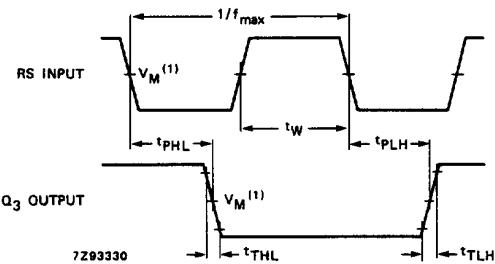
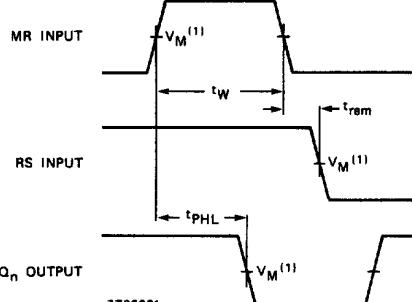


Fig.11 External components connection for a crystal oscillator.

AC WAVEFORMS

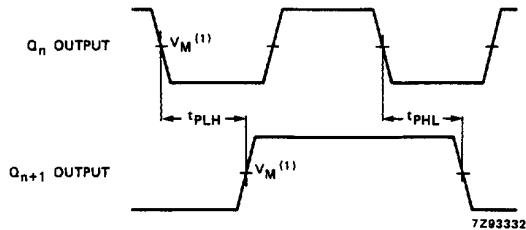
(1) HC : $V_M = 50\%$; $V_I = \text{GND to } V_{CC}$.
HCT: $V_M = 1.3 \text{ V}$; $V_I = \text{GND to } 3 \text{ V}$.

Fig.12 Waveforms showing the clock (RS) to output (Q_3) propagation delays, the clock pulse width, the output transition times and the maximum clock frequency.

(1) HC : $V_M = 50\%$; $V_I = \text{GND to } V_{CC}$.
HCT: $V_M = 1.3 \text{ V}$; $V_I = \text{GND to } 3 \text{ V}$.

Fig.13 Waveforms showing the master reset (MR) pulse width, the master reset to output (Q_n) propagation delays and the master reset to clock (RS) removal time.

(1) HC : $V_M = 50\%$; $V_I = \text{GND to } V_{CC}$.
HCT: $V_M = 1.3 \text{ V}$; $V_I = \text{GND to } 3 \text{ V}$.

Fig.14 Waveforms showing the output (Q_n) to Q_{n+1} propagation delays.**PACKAGE OUTLINES**

See "74HC/HCT/HCU/HCMOS Logic Package Outlines".

74HC/HCT4060; 14-stage binary ripple counter with oscillator

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General description

The 74HC/HCT4060 are high-speed Si-gate CMOS devices and are pin compatible with '4060' of the '4000B' series. They are specified in compliance with JEDEC standard no. 7A.

The 74HC/HCT4060 are 14-stage ripple-carry counter/dividers and oscillators with three oscillator terminals (RS, R_{TC} and C_{TC}), ten buffered outputs (Q₃ to Q₉ and Q₁₁ to Q₁₃) and an overriding asynchronous master reset (MR). The oscillator configuration allows design of either RC or crystal oscillator circuits. The oscillator may be replaced by an external clock signal at input RS. In this case keep the other oscillator pins (R_{TC} and C_{TC}) floating.

The counter advances on the negative-going transition of RS. A HIGH level on MR resets the counter (Q₃ to Q₉ and Q₁₁ to Q₁₃ = LOW), independent of other input conditions.

In the HCT version, the MR input is TTL compatible, but the RS input has CMOS input switching levels and can be driven by a TTL output by using a pull-up resistor to V_{CC}.

Features

- All active components on chip
- RC or crystal oscillator configuration
- Output capability: standard (except for R_{TC} and C_{TC})
- I_{CC} category: MSI

Datasheet

Type number	Title	Publication release date	Datasheet status	Page count	File size (kB)	Datasheet
74HC/HCT4060	14-stage binary ripple counter with oscillator	12/1/1990	Product specification	12	81	Download

[Additional datasheet info](#)

To complete the device datasheet with package and family information, also download the following PDF files. The "Logic Package Information" document is required to determine in which package(s) this device is available.

Document	Description
1 HCT_FAMILY_SPECIFICATIONS	HC/T Family Specifications, The IC06 74HC/HCT/HCMOS Logic Family Specifications
2 HCT_PACKAGE_INFO	HC/T Package Info, The IC06 74HC/HCT/HCMOS Logic Package Information
3 HCT_PACKAGE_OUTLINES	HC/T Package Outlines, The IC06 74HC/HCT/HCMOS Logic Package Outlines

▣ Parametrics

Type number	Package	Description	Propagation Delay(ns)	Voltage	No. of Pins	Power Dissipation Considerations	Logic Levels	Output Drive Capability
74HC4060D	SOT109 (SO16)	14-Stage Ripple-Carry Binary Counter/Divider and Oscillator	15	5 Volts +	16	Low Power or Battery Applications	CMOS	Low
74HC4060DB	SOT338-1 (SSOP16)	14-Stage Ripple-Carry Binary Counter/Divider and Oscillator	15	5 Volts +	16	Low Power or Battery Applications	CMOS	Low
74HC4060N	SOT38-1 (DIP16)	14-Stage Ripple-Carry Binary Counter/Divider and Oscillator	15	5 Volts +	16	Low Power or Battery Applications	CMOS	Low
74HC4060PW	SOT403-1 (TSSOP16)	14-Stage Ripple-Carry Binary Counter/Divider and Oscillator	15	5 Volts +	16	Low Power or Battery Applications	CMOS	Low
74HCT4060D	SOT109 (SO16)	14-Stage Ripple-Carry Binary Counter/Divider and Oscillator; TTL Enabled	15	5 Volts +	16	Low Power or Battery Applications	TTL	Low
74HCT4060DB	SOT338-1 (SSOP16)	14-Stage Ripple-Carry Binary Counter/Divider and Oscillator; TTL Enabled	15	5 Volts +	16	Low Power or Battery Applications	TTL	Low
74HCT4060N	SOT38-1 (DIP16)	14-Stage Ripple-Carry Binary Counter/Divider and Oscillator; TTL Enabled	15	5 Volts +	16	Low Power or Battery Applications	TTL	Low

▣ Products, packages, availability and ordering

Type number	North American type number	Ordering code (12NC)	Marking/Packing	Package	Device status	Buy online
			 Discretes packing info			
74HC4060D	74HC4060D	9337 140 10652	Standard Marking * Bulk Pack, CECC	SOT109 (SO16)	Full production	Order this
	74HC4060D-T	9337 140 10653	Standard Marking * Reel Pack, SMD, 13", CECC	SOT109 (SO16)	Full production	Order this
74HC4060DB	74HC4060DB	9351 875 00112	Standard Marking * Bulk Pack	SOT338-1 (SSOP16)	Full production	Order this
	74HC4060DB-T	9351 875 00118	Standard Marking * Reel Pack, SMD, 13"	SOT338-1 (SSOP16)	Full production	Order this
74HC4060N	74HC4060N	9336 697 70652	Standard Marking * Bulk Pack, CECC	SOT38-1 (DIP16)	Full production	Order this
74HC4060PW	74HC4060PW	9352 420 80112	Standard Marking * Bulk Pack	SOT403-1 (TSSOP16)	Full production	Order this
	74HC4060PW-T	9352 420 80118	Standard Marking * Reel Pack, SMD, 13"	SOT403-1 (TSSOP16)	Full production	Order this
74HCT4060D	74HCT4060D	9337 140 20652	Standard Marking * Bulk Pack, CECC	SOT109 (SO16)	Full production	Order this
	74HCT4060D-T	9337 140 20653	Standard Marking * Reel Pack, SMD, 13", CECC	SOT109 (SO16)	Full production	Order this
74HCT4060DB	74HCT4060DB	9351 900 20112	Standard Marking * Bulk Pack	SOT338-1 (SSOP16)	Full production	Order this
	74HCT4060DB-T	9351 900 20118	Standard Marking * Reel Pack, SMD, 13"	SOT338-1 (SSOP16)	Full production	Order this
74HCT4060N	74HCT4060N	9336 704 00652	Standard Marking * Bulk Pack, CECC	SOT38-1 (DIP16)	Full production	Order this

▣ Similar products

 [74HC/HCT4060](#) links to the similar products page containing an overview of products that are similar in function or related to the type number(s) as listed on this page. The similar products page includes products from the same catalog tree(s), relevant selection guides and products from the same functional category.

▣ Support & tools

 [HC/T Family Specifications, The IC06 74HC/HCT/HCMOS Logic Family Specifications](#)(date 01-Mar-98)
 [HC/T User Guide](#)(date 01-Nov-97)

Email/translate this product information

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